NSN 5962-00-007-7894

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View Online at https://aerobasegroup.com/nsn/5962-00-007-7894

Body Length:

Between 1.200 inches and 1.290 inches

Body Width:

Between 0.515 inches and 0.525 inches

Body Height:

Between 0.130 inches and 0.180 inches

Maximum Power Dissipation Rating:

625.0 milliwatts

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Hermetically sealed and monolithic and w/enable and negative outputs and positive outputs and programmable and programmed and

w/storage

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

P-type metal oxide-semiconductor logic

Input Circuit Pattern:

11 input

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-8.0 volts power source and 12.3 volts power source

Time Rating Per Chacteristic:

650.00 nanoseconds propagation delay time, low to high level output and 650.00 nanoseconds propagation delay time, high to low level output

Memory Device Type:

Rom

Memory Capacity:

Unknown

Test Data Document:

05869-717382-4 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

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